

Silicon N Channel MOS Type / Silicon Epitaxial Planer Diode

SSM5H90TU

High-Speed Switching Applications

- Integrates an N-ch MOSFET and planer diodes into one package.
- Low $R_{DS(ON)}$ and low V_F

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$) for the MOSFET

Characteristics	Symbol	Rating	Unit
Drain-Source voltage	V_{DSS}	20	V
Gate-Source voltage	V_{GSS}	± 10	V
Drain current	DC	I_D	A
	Pulse	I_{DP} (Note 2)	
Drain power dissipation	P_D (Note 1)		W
		$t = 10\text{s}$	
Channel temperature	T_{ch}	150	$^\circ\text{C}$

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$) for the Diodes

Characteristics	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V_{RM}	85	V
Reverse voltage	V_R	80	V
Maximum (peak) forward current	I_{FM}	300	mA
Average forward current	I_O	100	mA
Surge current (10ms)	I_{FSM}	2	A
Junction temperature	T_j	125	$^\circ\text{C}$

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$) for the MOSFET and Diodes

Characteristics	Symbol	Rating	Unit
Storage temperature	T_{stg}	-55 to 125	$^\circ\text{C}$

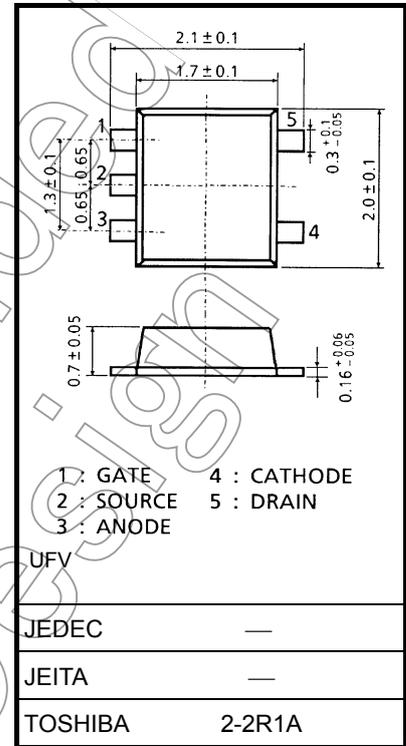
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

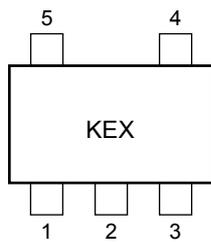
Note 1: Mounted on a FR4 board.
(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm²)

Note 2: Puls width limited by max channel temperature

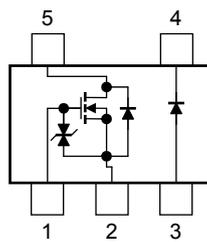
Unit: mm



Marking



Equivalent Circuit



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic discharge. Operators should wear anti-static clothing and use containers and other objects that are made of anti-static materials.

The Channel-to-Ambient thermal resistance $R_{th(ch-a)}$ and the drain power dissipation P_D vary according to the board material, board area, board thickness and pad area. When using this device, please take heat dissipation fully into account.

Not Recommended for New Design

MOSFET

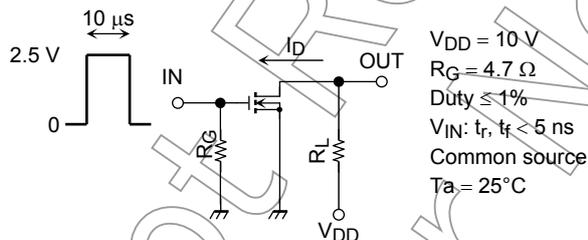
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	20	—	—	V
	$V_{(BR)DSX}$	$I_D = 1 \text{ mA}, V_{GS} = -10 \text{ V}$	12	—	—	
Drain cutoff current	I_{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	1	μA
Gate leakage current	I_{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	± 1	μA
Gate threshold voltage	V_{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.35	—	1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3 \text{ V}, I_D = 1.0 \text{ A}$ (Note 3)	3.5	7	—	S
Drain-Source ON-resistance	$R_{DS(ON)}$	$I_D = 1.5 \text{ A}, V_{GS} = 4.0 \text{ V}$ (Note 3)	—	53	65	m Ω
		$I_D = 1.5 \text{ A}, V_{GS} = 2.5 \text{ V}$ (Note 3)	—	63	80	
		$I_D = 1.0 \text{ A}, V_{GS} = 1.8 \text{ V}$ (Note 3)	—	77	110	
		$I_D = 0.5 \text{ A}, V_{GS} = 1.5 \text{ V}$ (Note 3)	—	92	157	
Input capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	400	—	pF
Output capacitance	C_{oss}		—	68	—	
Reverse transfer capacitance	C_{rss}		—	60	—	
Total Gate Charge	Q_g	$V_{DS} = 10 \text{ V}, I_{DS} = 2.4 \text{ A}, V_{GS} = 4 \text{ V}$	—	6.3	—	nC
Gate-Source Charge	Q_{gs}		—	4.3	—	
Gate-Drain Charge	Q_{gd}		—	2.0	—	
Switching time	Turn-on time	$V_{DD} = 10 \text{ V}, I_D = 2 \text{ A}, V_{GS} = 0 \text{ to } 2.5 \text{ V}, R_G = 4.7 \Omega$	—	14	—	ns
	Turn-off time		—	15	—	
Drain-Source forward voltage	V_{DSF}	$I_D = -2.4 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 3)	—	-0.85	-1.2	V

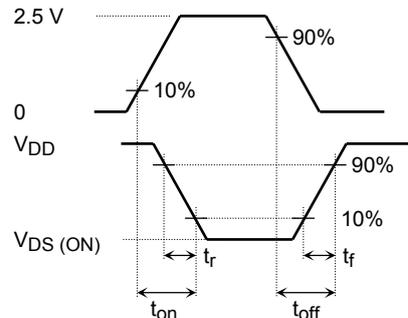
Note 3: Pulse measurement

Switching Time Test Circuit

(a) Test circuit



(b) V_{IN}



(c) V_{OUT}

Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the SSM5H90TU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

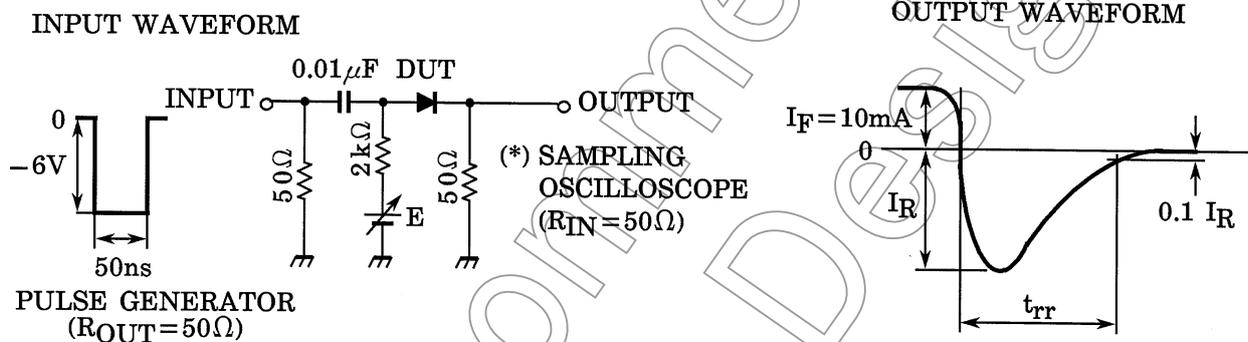
Take this into consideration when using the device.

Planer Diodes

Electrical Characteristics (Ta = 25°C)

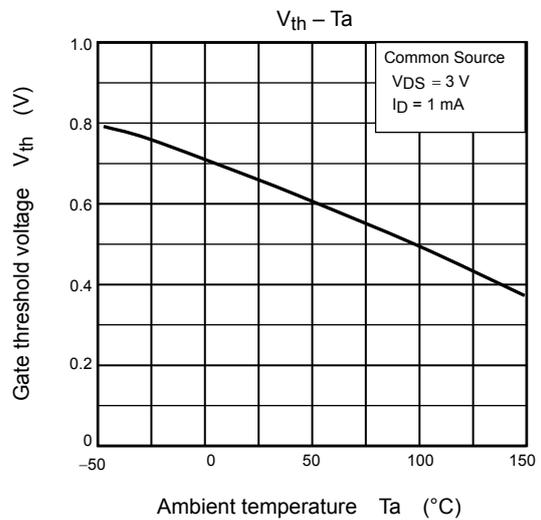
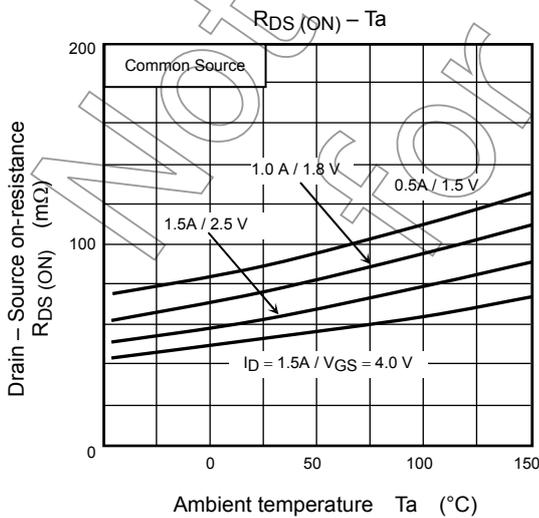
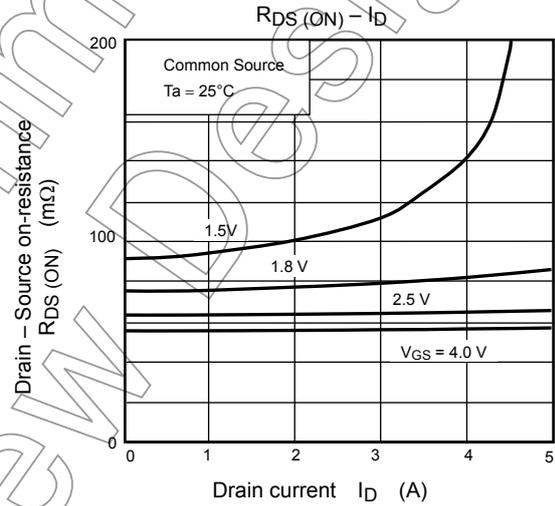
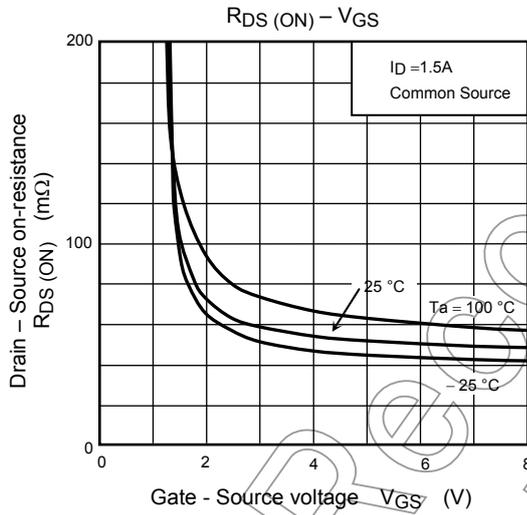
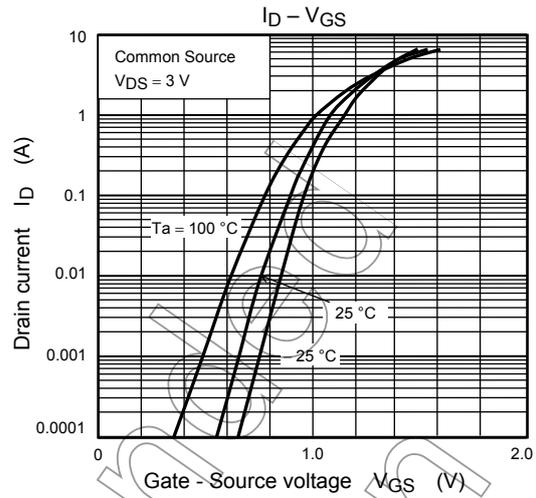
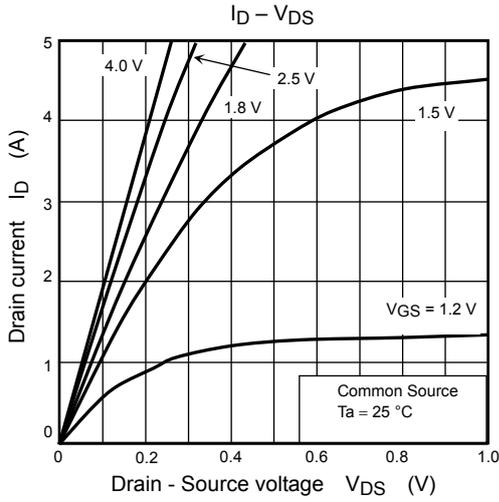
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Forward voltage	V _F (1)	I _F = 1mA	—	0.60	—	V
	V _F (2)	I _F = 10mA	—	0.72	—	
	V _F (3)	I _F = 100mA	—	0.90	1.20	
Reverse current	I _R (1)	V _R = 30V	—	—	0.1	μA
	I _R (2)	V _R = 80V	—	—	0.5	
Total capacitance	C _T	V _R = 0, f = 1MHz	—	0.9	—	pF
Reverse recovery time	t _{rr}	I _F = 10mA (Note.4)	—	1.6	—	ns

Note 4: Reverse recovery time (t_{rr}) test circuit

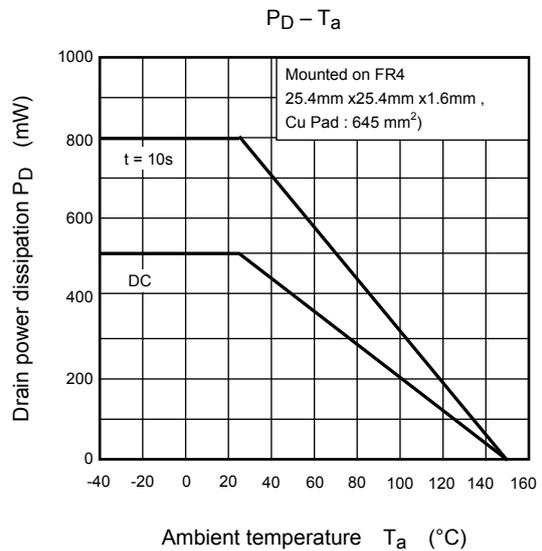
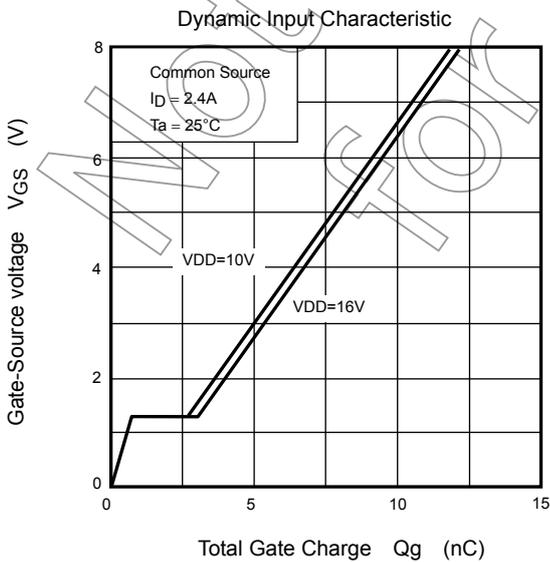
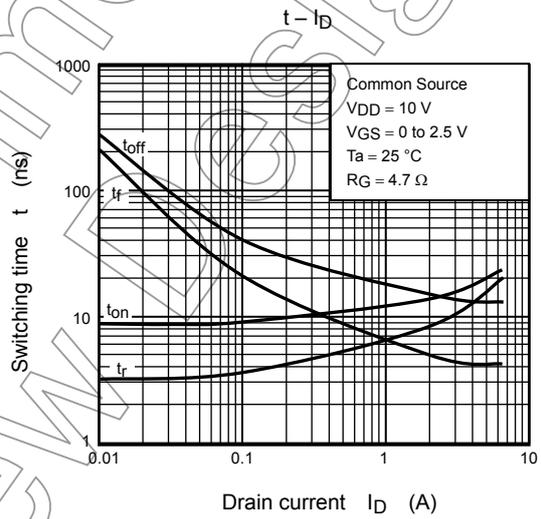
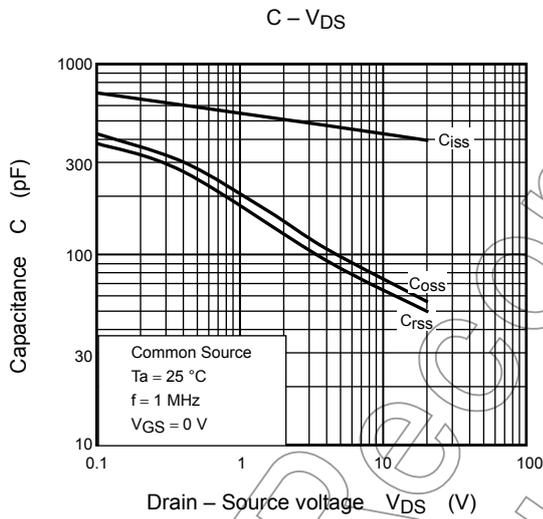
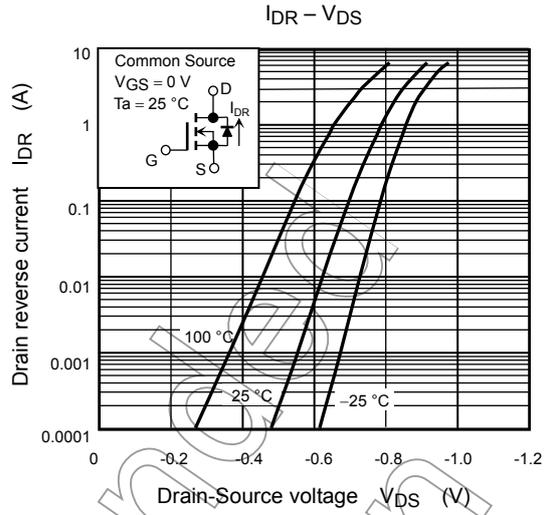
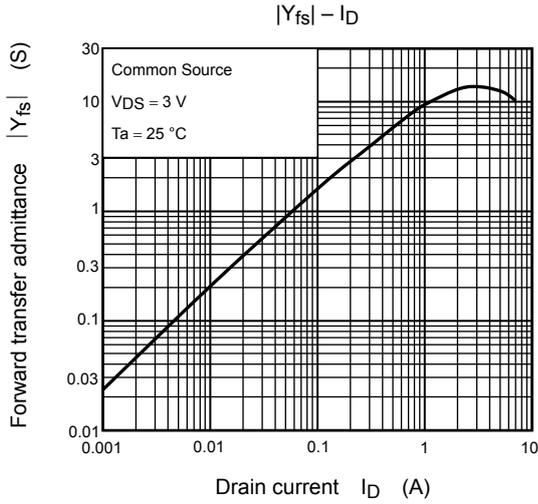


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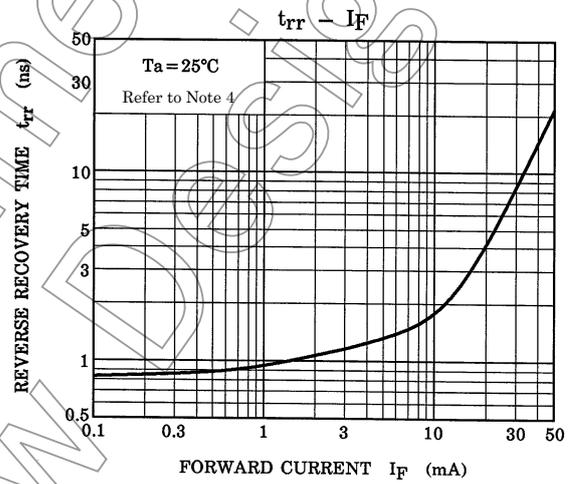
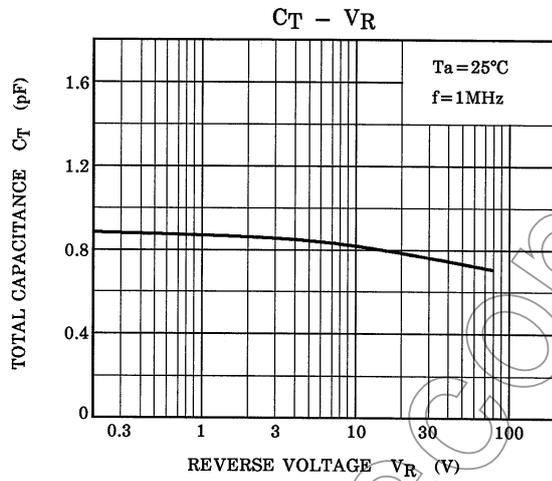
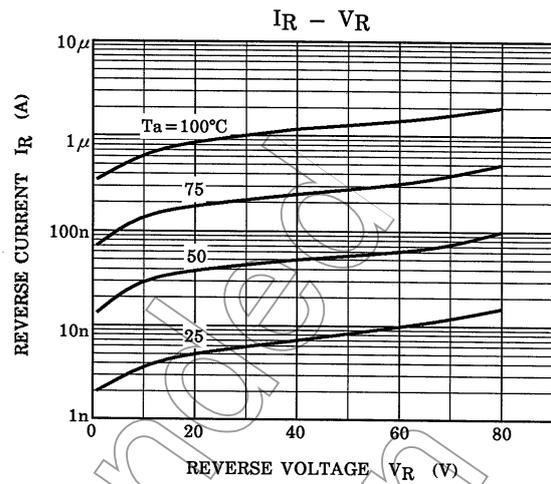
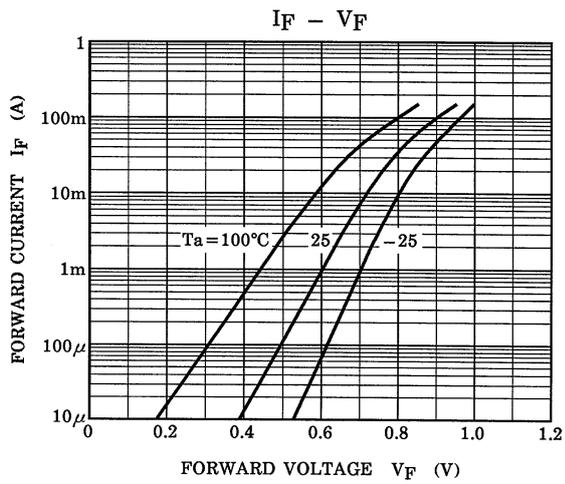
Electrical Characteristics Graph for the MOSFET



Electrical Characteristics Graph for the MOSFET



Electrical Characteristics Graph for the Planer Diodes



Not Recommended for New Design

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